

2SD647A
2SD697A

SILICON NPN TRIPLE DIFFUSED MESA TYPE
(DARLINGTON POWER)

INDUSTRIAL APPLICATIONS

Unit in mm

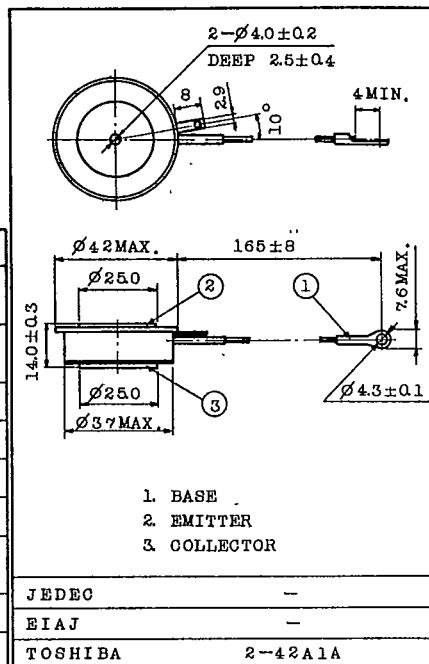
HIGH POWER SWITCHING APPLICATIONS.
DC-AC POWER INVERTER APPLICATIONS.
MOTOR CONTROL APPLICATIONS.

FEATURES:

- High Voltage : $V_{CEO(SUS)} \geq 450V$ (2SD697A)
- Triple Diffused Design.
- Darlington Design.

MAXIMUM RATINGS. ($T_a=25^\circ C$)

CHARACTERISTIC	SYMBOL	RATING	UNIT
Collector-Base Voltage	2SD647A	800	V
	2SD697A	500	
Collector-Emitter Voltage	2SD647A	600	V
	2SD697A	450	
Emitter-Base Voltage	V_{EBO}	5	V
Collector Current	I_C	100	A
Emitter Current	I_E	-100	A
Base Current	I_B	6	A
Thermal Resistance (Double Side Cooling)	$R_{th(j-c)}$	0.13	$^\circ C/W$
Junction Temperature	T_j	125	$^\circ C$
Storage Temperature Range	T_{stg}	-40 ~ 150	$^\circ C$
Mounting Force Required	F	400±40	kg



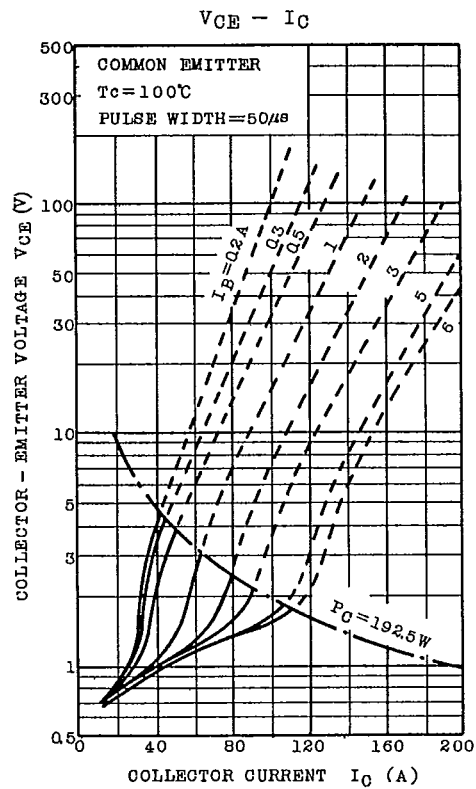
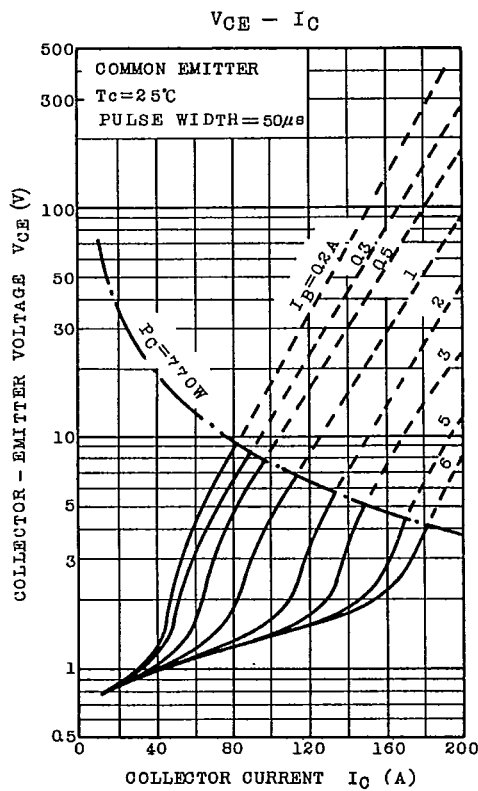
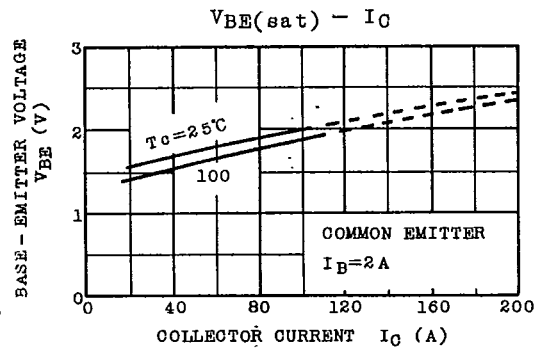
Weight : 70g

ELECTRICAL CHARACTERISTICS ($T_a=25^\circ C$)

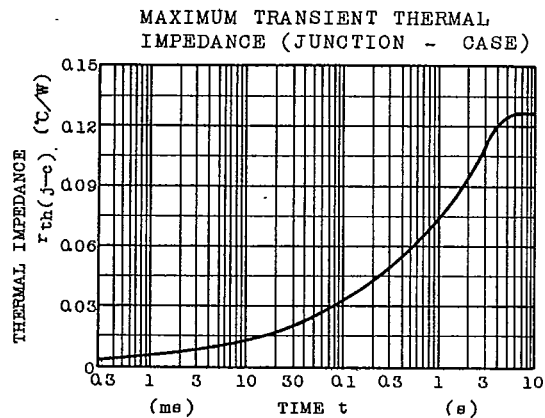
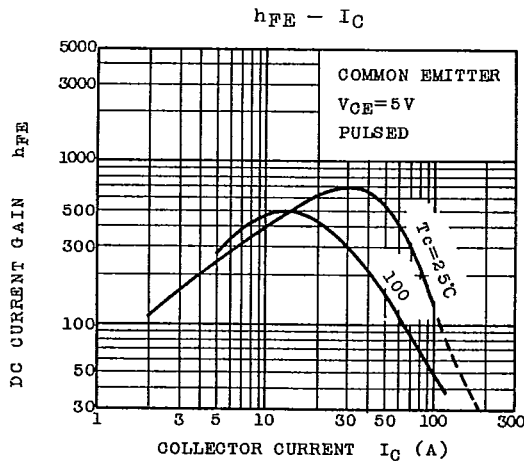
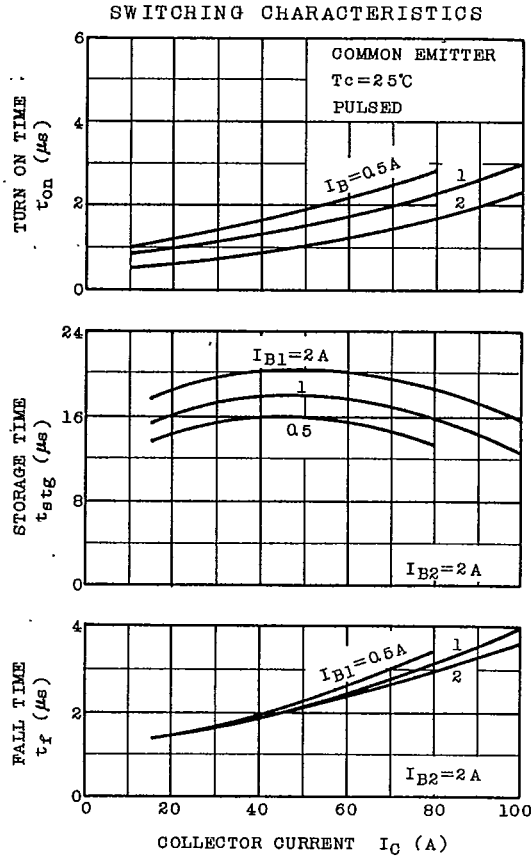
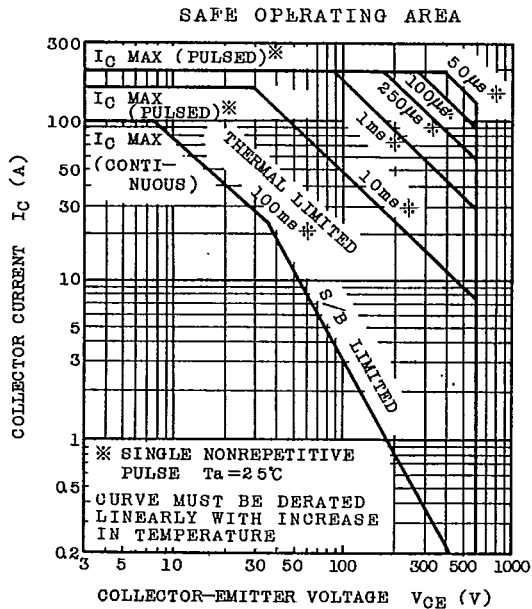
CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
DC Current Gain	h_{FE}	$V_{CE}=5V, I_C=100A$	100	—	—	
		$V_{CE}=5V, I_C=50A$	—	500	—	
Collector-Emitter Sustaining Voltage	2SD647A 2SD697A	$V_{CEO(SUS)}$ $I_C=0.5A, L=40mH$	600 450	—	—	V
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C=100A, I_B=2A$ (Note)	—	—	2.0	V
Base-Emitter Saturation Voltage	$V_{BE(sat)}$		—	—	2.5	V
Collector Cut-off Current	2SD647A 2SD697A	I_{CBO} $V_{CB}=800V, I_E=0$ $V_{CB}=500V, I_E=0$	—	—	2	mA
			—	—	2	
Emitter Cut-off Current	I_{EBO}	$V_{EB}=5V, I_C=0$	—	—	200	mA
Switching Time	Turn-on Time	$I_C=100A, I_{B1}=2A,$ $-I_{B2}=2A, V_C=300V$	—	2.5	—	μs
	Storage Time		—	20	—	μs
	Fall Time		—	4	—	μs

Note : Pulse Test; Pulse Width $\leq 300\mu s$, Duty Cycle $\leq 3\%$
Mounting Force; F=400kg

TOSHIBA CORPORATION



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